



60V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D T _C = +25°C
60V	$1.6m\Omega$ @ VGS = $10V$	215A

Features

- Rated to +175°C Ideal for High Ambient Temperature **Environments**
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- High-Conversion Efficiency
- Low R_{DS(ON)} Minimizes on State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMTH61M8SPSQ)

Description and Applications

This new generation N-channel enhancement mode MOSFET is designed to minimize RDS(ON) yet maintain superior switching performance. This device is ideal for use in power management and load switch.

- **Engine Management Systems**
- **Body Control Electronics**
- DC-DC Converters

Mechanical Data

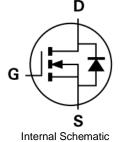
- Case: PowerDI®5060-8 Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 63
- Weight: 0.097 grams (Approximate)

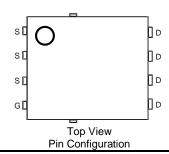
PowerDI5060-8 (Type K)



Ordering Information (Note 4)







Top View **Bottom View**

Part Number	Case	Packaging
DMTH61M8SPS-13	PowerDI5060-8 (Type K)	2,500 / Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



⊃¦¦ = Manufacturer's Marking TH61M8SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 21 = 2021) WW = Week (01 to 53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V_{DSS}	60	V	
Gate-Source Voltage	Vgss	±20	V	
Continuous Drain Current, $V_{GS} = 10V$ (Note 6) $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$		I _D	215 150	А
Maximum Continuous Body Diode Forward Current (Note 6)	Is	215	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	860	Α	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle =	lsм	860	Α	
Avalanche Current, L = 1mH	las	35.8	А	
Avalanche Energy, L = 1mH		Eas	640.8	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.2	W
Thermal Resistance, Junction to Ambient (Note 5)		RθJA	47	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	167	W
Thermal Resistance, Junction to Case (Note 6)		Rелс	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

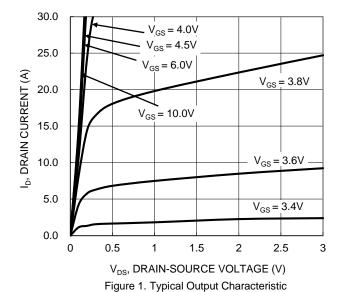
		,		,			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	_		V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	V _{DS} = 48V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	1.1	1.6	mΩ	$V_{GS} = 10V, I_D = 30A$	
Diode Forward Voltage	VsD	_	0.7	1.2	V	Vgs = 0V, Is = 20A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	8306	_		V _{DS} = 30V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	2735	_	pF		
Reverse Transfer Capacitance	Crss	_	184	_			
Gate Resistance	Rg	_	3.0	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg	_	130.6	_		V _{DS} = 30V, I _D = 30A, V _{GS} = 10V	
Gate-Source Charge	Qgs	_	30.4	_	nC		
Gate-Drain Charge	Q_{gd}	_	28.1	_			
Turn-On Delay Time	tD(ON)	_	11.3	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 30A, R_g = 3\Omega$	
Turn-On Rise Time	t _R	_	28.5	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	86.2	_	115		
Turn-Off Fall Time	tF	_	47.6	_			
Body Diode Reverse Recovery Time	trr	_	70.4		ns	1- 200 4:/44 4000/	
Body Diode Reverse Recovery Charge	Q _{RR}	_	127	_	nC	$=$ IF = 30A, di/dt = 100A/ μ s	

5. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. Notes:

8. Guaranteed by design. Not subject to product testing.

^{6.} Thermal resistance from junction to soldering point (on the exposed drain pad).7. Short duration pulse test used to minimize self-heating effect.





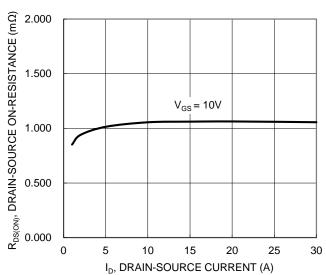
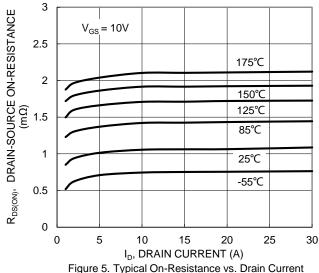


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage



and Temperature

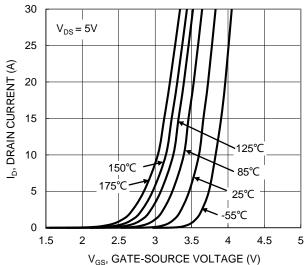


Figure 2. Typical Transfer Characteristic

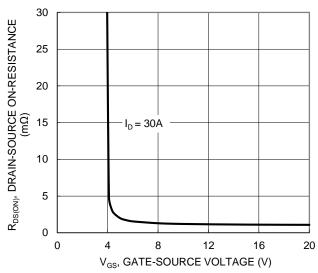


Figure 4. Typical Transfer Characteristic

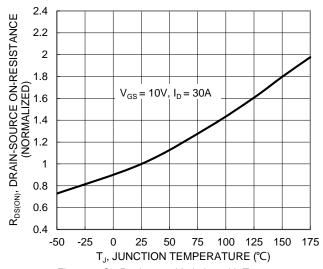


Figure 6. On-Resistance Variation with Temperature



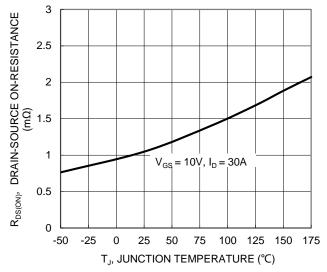


Figure 7. On-Resistance Variation with Temperature

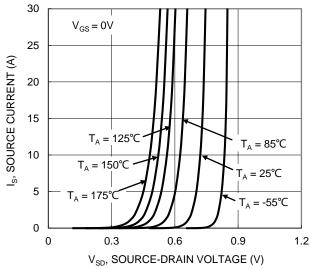


Figure 9. Diode Forward Voltage vs. Current

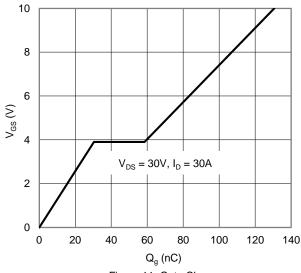


Figure 11. Gate Charge

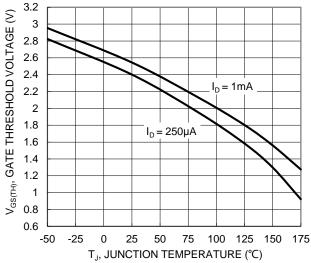
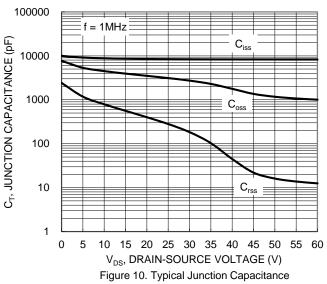


Figure 8. Gate Threshold Variation vs. Junction Temperature



1000 R_{DS(ON)} 100 ID, DRAIN CURRENT (A) 10 T_{J(Max)} = 175 °C $P_W = 10m$ T_C = 25°C $P_W = 100 ms$ Single Pulse DUT on Infinite DC Heatsink $V_{GS} = 10V$ 0.1 0.1 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



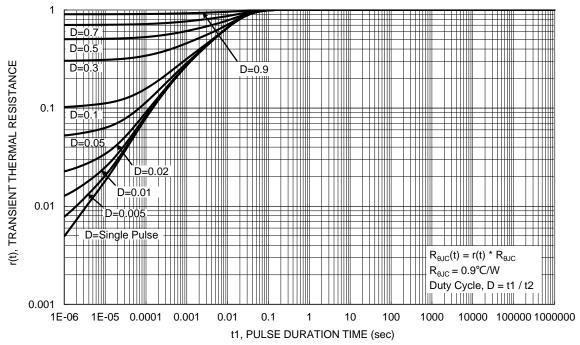


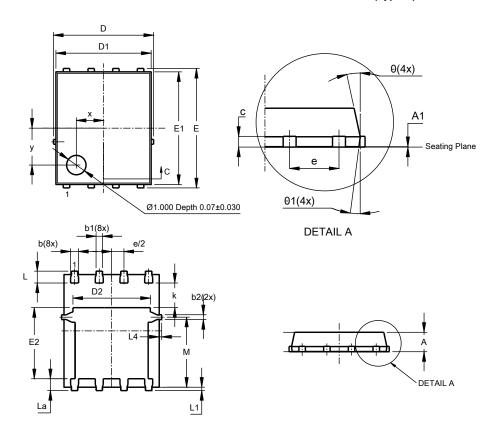
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type K)

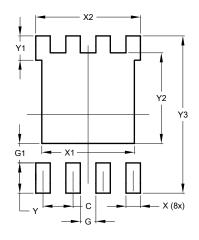


PowerDI5060-8 (Type K)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05	0.02	
b	0.33	0.51	0.41	
b1	0.300	0.366	0.333	
b2	0.20	0.35	0.25	
C	0.23	0.33	0.277	
D	5	.15 BS0		
D1	4.85	4.95	4.90	
D2	-	-	3.98	
Е	6	.15 BS0		
E1	5.75	5.85	5.80	
E2	3.56	3.725	3.66	
е	1	.27BSC		
k	-	-	1.27	
L	0.51	0.71	0.61	
La	0.51	0.675	0.61	
L1	0.05	0.20	0.175	
L4	-	-	0.125	
M	3.50	3.71	3.605	
Х	-	-	1.400	
y θ	-	-	1.900	
	10°	12°	11°	
θ1	6°	8°	7°	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8 (Type K)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
X	0.610		
X1	3.910		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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